

1A, 200V - 1000V Surface Mount Fast Recovery Rectifier

FEATURES

- Glass passivated junction chip
- Ideal for automated placement
- Low profile package
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- High frequency rectification
- Freewheeling application
- Switching mode converters and inverters in computer, automotive and telecommunication

MECHANICAL DATA

- Case: SOD-128
- Molding compound meets UL 94V-0 flammability rating
- Part no. with suffix "H" means AEC-Q101 qualified
- Packing code with suffix "G" means green compound (halogen-free)
- Moisture sensitivity level: level 1, per J-STD-020
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.027 g (approximately)

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I _{F(AV)}	1	А		
V _{RRM}	200 - 1000	V		
I _{FSM}	30	А		
T _{J MAX}	150	°C		
Package	SOD-128			
Configuration	Single die			





SOD-128

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)							
PARAMETER	SYMBOL	RS1DFS	RS1GFS	RS1JFS	RS1KFS	RS1MFS	UNIT
Marking code on the device		RS1DFS	RS1GFS	RS1JFS	RS1KFS	RS1MFS	
Repetitive peak reverse voltage	V _{RRM}	200	400	600	800	1000	V
Reverse voltage, total rms value	V _{R(RMS)}	140	280	420	560	700	V
Forward current	I _{F(AV)}			1			А
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}			30			A
Junction temperature	TJ			- 55 to +150)		°C
Storage temperature	T _{STG}			- 55 to +150)		°C



THERMAL PERFORMANCE					
PARAMETER	SYMBOL	ТҮР	UNIT		
Junction-to-lead thermal resistance per diode	R _{ejl}	29	°C/W		
Junction-to-ambient thermal resistance per diode	R _{θJA}	84	°C/W		
Junction-to-case thermal resistance per diode	R _{eJC}	30	°C/W		

Thermal Performance Note: Units mounted on recommended PCB (5mm x 5mm Cu pad test board)

ELECTRICAL SPECIFICATIONS ($T_A = 25^{\circ}C$ unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage per diode ⁽¹⁾		$I_F = 0.5A, T_J = 25^{\circ}C$		0.94	1.10	V
		$I_F = 1.0A, T_J = 25^{\circ}C$		1.01	1.30	
		$I_F = 0.5A, T_J = 125^{\circ}C$	V _F	0.79	1.00	
		$I_F = 1.0A, T_J = 125^{\circ}C$		0.88	1.20	
Reverse current @ rated V_R per diode $^{(2)}$		$T_J = 25^{\circ}C$	- I _R	-	5	μA
		T _J = 125°C		-	50	μA
Junction capacitance		1 MHz, V _R =4.0V	CJ	7	-	pF
	RS1DFS RS1GFS	I _F =0.5A ,I _R =1.0A I _{RR} =0.25A	t _{rr}	-	150	ns
Reverse recovery time	RS1JFS			-	250	ns
	RS1KFS RS1MFS			-	500	ns

Notes:

1. Pulse test with PW=0.3 ms

2. Pulse test with PW=30 ms

ORDERING INFORMATION					
PART NO.	PART NO. SUFFIX(*)	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING
RS1xFS		MW	0	SOD-128	3,500 / 7" Plastic reel
(Note 1, 2)	H	MX	G	SOD-128	14,000 / 13" Plastic reel

Notes:

1. "xx" defines voltage from 200V (RS1DFS) to 1000V (RS1MFS)

2. Whole series with green compound (halogen-free)

*: Optional available

EXAMPLE P/N					
EXAMPLE P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
RS1DFSHMWG	RS1DFS	Н	MW	G	AEC-Q101 qualified Green compound



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

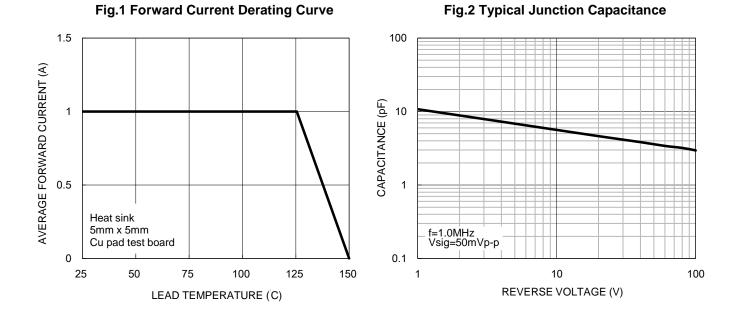


Fig.3 Typical Reverse Characteristics

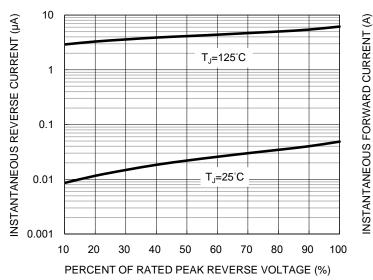
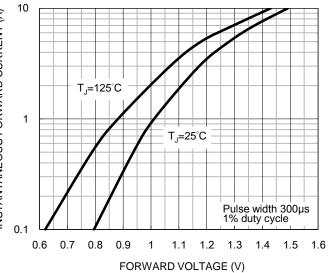


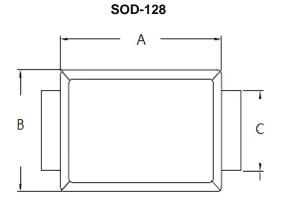
Fig.4 Typical Forward Characteristics

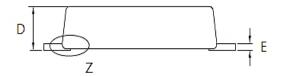


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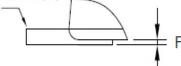


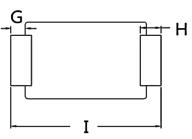
PACKAGE OUTLINE DIMENSIONS



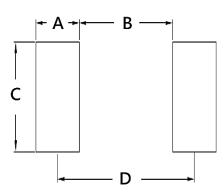


BURR SIDE (Z)





SUGGESTED PAD LAYOUT



DIM Unit (mm) Unit (inch) А 1.40 0.055 В 3.00 0.118 С 2.10 0.082 D 4.40 0.173

MARKING DIAGRAM



DIM	Unit	(mm)	Unit (inch)		
DIN	Min	Max	Min	Max	
А	3.60	4.00	0.142	0.157	
В	2.30	2.70	0.091	0.106	
С	1.60	1.90	0.063	0.075	
D	0.90	1.10	0.035	0.043	
E	0.10	0.22	0.004	0.009	
F	0.00	0.10	0.000	0.004	
G	0.30	0.60	0.012	0.024	
Н	0.40	0.80	0.016	0.031	
I	4.40	5.00	0.173	0.197	

P/N	= Marking Code
YW	= Date Code
F	= Factory Code



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RS1DFSHMWG RS1KFS MXG RS1MFSHMXG RS1DFS MWG RS1GFSHMXG RS1JFSHMXG RS1KFS MWG RS1JFSHMWG RS1MFS MWG RS1KFSHMXG RS1JFS MXG RS1DFSHMXG RS1DFS MXG RS1MFSHMWG RS1JFS MWG RS1GFS MXG RS1KFSHMWG RS1MFS MXG RS1GFSHMWG RS1GFS MWG RS1DFS RS1DFSH RS1GFS RS1GFSH RS1JFS RS1JFSH RS1KFS RS1KFSH RS1MFS RS1MFSH